

STD35NF06L

N-channel 60 V, 0.014 Ω 35 A STripFET™ II Power MOSFET in a DPAK package

Datasheet — production data

Features

Order code	V _{DSS}	R _{DS(on)}	I _D
STD35NF06LT4	60V	<0.017Ω	35A

- Low threshold drive
- Gate charge minimized

Applications

Switching application

Description

This Power MOSFET has been developed using STMicroelectronics' unique STripFET process, which is specifically designed to minimize input capacitance and gate charge. This renders the device suitable for use as primary switch in advanced high-efficiency isolated DC-DC converters for telecom and computer applications, and applications with low gate charge driving requirements.

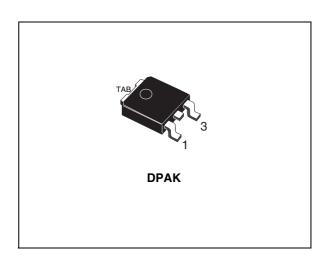


Figure 1. Internal schematic diagram

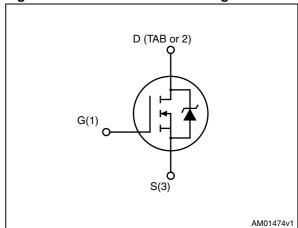


Table 1. Device summary

Order code	Marking Package		Packaging	
STD35NF06LT4	D35NF06L	DPAK	Tape and reel	

Contents STD35NF06L

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STD35NF06L Electrical ratings

1 Electrical ratings

Table 2. Absolute maximum ratings

Symbol	Parameter	Value	Unit
V _{DS}	Drain-source voltage	60	V
V _{DGR}	Drain-gate voltage ($R_{GS} = 20 \text{ k}\Omega$)	60	V
V _{GS}	Gate- source voltage	± 16	V
I _D	Drain current (continuous) at T _C = 25 °C	35	Α
I _D	Drain current (continuous) at T _C = 100 °C	24.5	Α
I _{DM} ⁽¹⁾	Drain current (pulsed)	140	Α
P _{tot}	Total dissipation at T _C = 25 °C	80	W
	Derating Factor	0.53	W/°C
dv/dt ⁽²⁾	Peak diode recovery avalanche energy	5	V/ns
E _{AS} (3)	Single pulse avalanche energy	280	mJ
T _{stg}	Storage temperature	-55 to 175	°C
T _j	Max. operating junction temperature	-55 to 175	

^{1.} Pulse width limited by safe operating area.

Table 3. Thermal data

Symbol	Parameter	Value	Unit
Rthj-case	Thermal resistance junction-case max	1.88	°C/W
Rthj-amb	Thermal resistance junction-to ambient max	100	°C/W
T _J	Maximum lead temperature for soldering purpose	275	°C

^{2.} $I_{SD} \leq 35~A,~di/dt \leq 100~A/\mu s,~V_{DD} = V(_{BR)DSS},~T_{j} \leq T_{JMAX}$

^{3.} Starting $T_j = 25$ °C, $I_D = 30$ A, $V_{DD} = 30$ V

Electrical characteristics STD35NF06L

2 Electrical characteristics

(T_{CASE} = 25 °C unless otherwise specified)

Table 4. On/off states

Symbol	Parameter Test conditions		Min.	Тур.	Max.	Unit
V _{(BR)DSS}	Drain-source breakdown voltage	$I_D = 250 \ \mu\text{A}, \ V_{GS} = 0$	60			V
I _{DSS}	Zero gate voltage drain current (V _{GS} = 0)	V _{DS} = 60 V V _{DS} = 60 V, T _C = 125 °C			1 10	μ Α μ Α
I _{GSS}	Gate-body leakage current (V _{DS} = 0)	V _{GS} = ± 16 V			±100	nA
V _{GS(th)}	Gate threshold voltage	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	1		2.5	V
R _{DS(on)}	Static drain-source on-resistance	$V_{GS} = 10 \text{ V}, I_D = 17.5 \text{ A}$ $V_{GS} = 4.5 \text{ V}, I_D = 17.5 \text{ A}$		0.014 0.016	0.017 0.020	Ω Ω

Table 5. Dynamic

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
9 _{fs} ⁽¹⁾	Forward transconductance	V _{DS} = 15 V, I _D = 17.5 A	-	28		S
C _{iss} C _{oss} C _{rss}	Input capacitance Output capacitance Reverse transfer capacitance	V _{DS} = 25 V, f = 1 MHz, V _{GS} = 0	-	1700 305 105		pF pF pF
$\begin{array}{c} t_{d(on)} \\ t_{r} \\ t_{d(off)} \\ t_{f} \end{array}$	Turn-on delay time Rise time Turn-off delay time Fall time	$V_{DD} = 30 \text{ V}, I_{D} = 27.5 \text{ A}$ $R_{G} = 4.7 \Omega V_{GS} = 4.5 \text{ V}$ (see <i>Figure 13</i>)	-	20 100 40 20		ns ns ns
Q _g Q _{gs} Q _{gd}	Total gate charge Gate-source charge Gate-drain charge	$V_{DD} = 48 \text{ V}, I_{D} = 55 \text{ A},$ $V_{GS} = 4.5 \text{ V}, R_{G} = 4.7 \Omega$ (see <i>Figure 14</i>)	-	25 5 10	33	nC nC nC

^{1.} Pulsed: pulse duration = 300 μ s, duty cycle 1.5%.

Table 6. Source drain diode

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
I _{SD}	Source-drain current Source-drain current (pulsed)		-		35 140	A A
V _{SD} ⁽²⁾	Forward on voltage	I _{SD} = 35 A, V _{GS} = 0	-		1.5	V
t _{rr} Q _{rr} I _{RRM}	Reverse recovery time Reverse recovery charge Reverse recovery current	$I_{SD} = 35 \text{ A},$ $di/dt = 100 \text{ A/}\mu\text{s},$ $V_{DD} = 30 \text{ V}, T_j = 150 ^{\circ}\text{C}$ (see <i>Figure 15</i>)	-	80 200 5		ns nC A

^{1.} Pulse width limited by safe operating area.

^{2.} Pulsed: Pulse duration = $300 \mu s$, duty cycle 1.5%

Electrical characteristics STD35NF06L

2.1 Electrical characteristics (curves)

Figure 2. Safe operating area

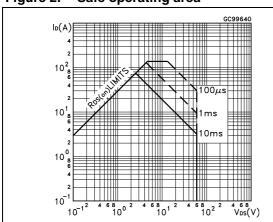


Figure 3. Thermal impedance

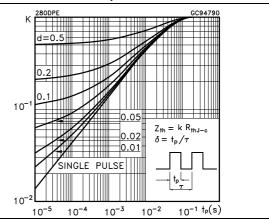


Figure 4. Output characteristics

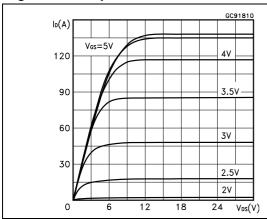


Figure 5. Transfer characteristics

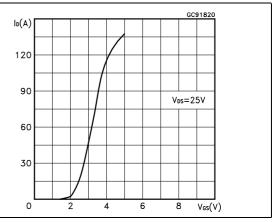


Figure 6. Transconductance

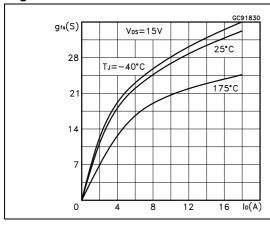


Figure 7. Static drain-source on-resistance

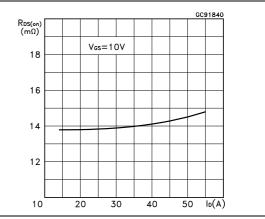
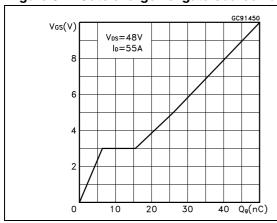


Figure 8. Gate charge vs. gate-source voltage Figure 9. Capacitance variations



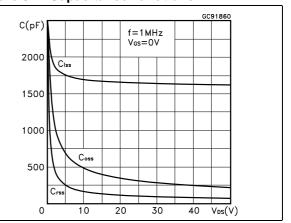
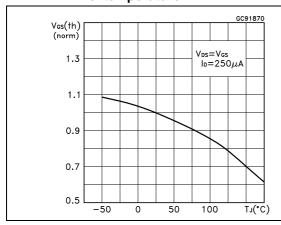


Figure 10. Normalized gate threshold voltage vs. temperature

Figure 11. Normalized on-resistance vs. temperature



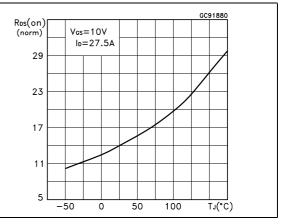
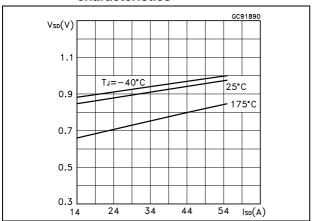


Figure 12. Source-drain diode forward characteristics



Test circuit STD35NF06L

3 Test circuit

Figure 13. Switching times test circuit for resistive load

Figure 14. Gate charge test circuit

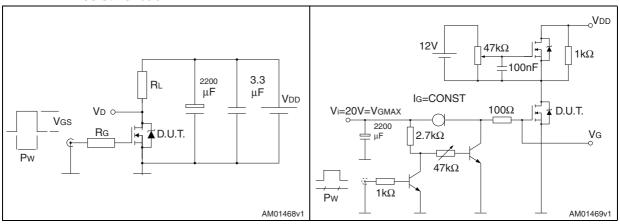


Figure 15. Test circuit for inductive load switching and diode recovery times

Figure 16. Unclamped Inductive load test circuit

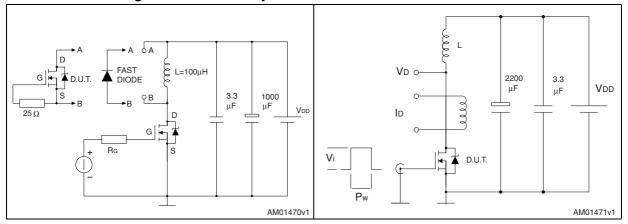
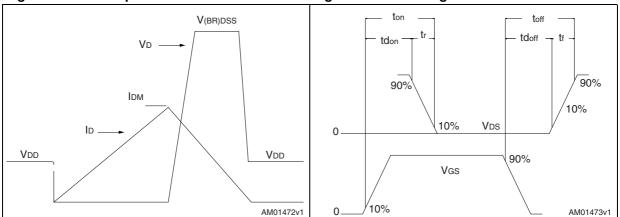


Figure 17. Unclamped inductive waveform

Figure 18. Switching time waveform



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4 Package mechanical data

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: www.st.com. ECOPACK is an ST trademark.

Table 7. DPAK (TO-252) mechanical data

Dim		mm	
Dim.	Min.	Тур.	Max.
Α	2.20		2.40
A1	0.90		1.10
A2	0.03		0.23
b	0.64		0.90
b4	5.20		5.40
С	0.45		0.60
c2	0.48		0.60
D	6.00		6.20
D1		5.10	
Е	6.40		6.60
E1		4.70	
е		2.28	
e1	4.40		4.60
Н	9.35		10.10
L	1		1.50
L1		2.80	
L2		0.80	
L4	0.60		1
R		0.20	
V2	0°		8°

Figure 19. DPAK (TO-252) drawing

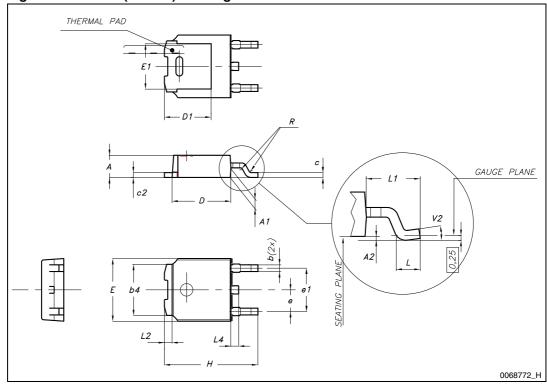
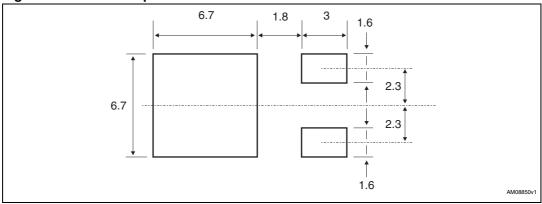


Figure 20. DPAK footprint^(a)



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a. All dimension are in millimeters

5 Packing mechanical data

Table 8. DPAK (TO-252) tape and reel mechanical data

	Таре			Reel	
Dim	n	nm	Dim	n	nm
Dim.	Min.	Max.	— Dim.	Min.	Max.
A0	6.8	7	А		330
В0	10.4	10.6	В	1.5	
B1		12.1	С	12.8	13.2
D	1.5	1.6	D	20.2	
D1	1.5		G	16.4	18.4
Е	1.65	1.85	N	50	
F	7.4	7.6	Т		22.4
K0	2.55	2.75			
P0	3.9	4.1		Base qty.	2500
P1	7.9	8.1		Bulk qty.	2500
P2	1.9	2.1			
R	40				
Т	0.25	0.35			
W	15.7	16.3			

Figure 21. Tape for DPAK (TO-252)

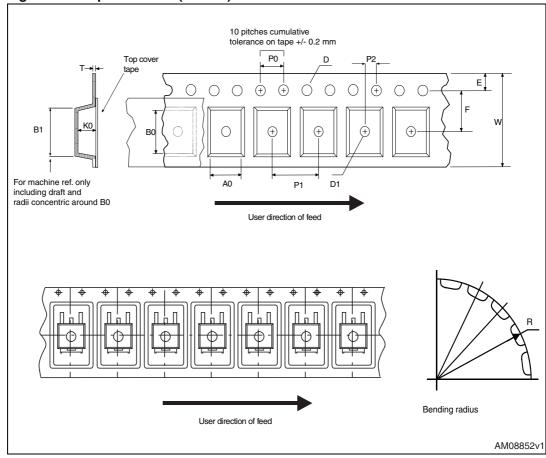
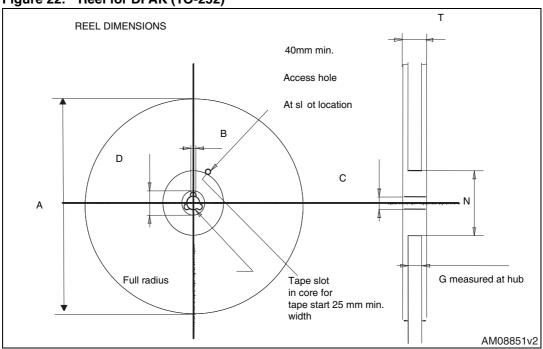


Figure 22. Reel for DPAK (TO-252)



STD35NF06L Revision history

6 Revision history

Table 9. Revision history

Date	Revision	Changes
21-Jun-2004	2	Preliminary version
06-Jul-2006	3	New template, no content change
20-Feb-2007	4	Typo mistake on page 1
19-Apr-2012	5	Added new value in <i>Table 4: On/off states</i> (V _{GS(th)} max). Minor text changes.

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